



T-46-13-29

NMC27C256

## NMC27C256 262,144-Bit (32k x 8) UV Erasable CMOS PROM

### General Description

The NMC27C256 is a high-speed 256k UV erasable and electrically reprogrammable CMOS EPROM, ideally suited for applications where fast turnaround, pattern experimentation and low power consumption are important requirements.

The NMC27C256 is designed to operate with a single +5V power supply with  $\pm 5\%$  or  $\pm 10\%$  tolerance. The CMOS design allows the part to operate over extended and military temperature ranges.

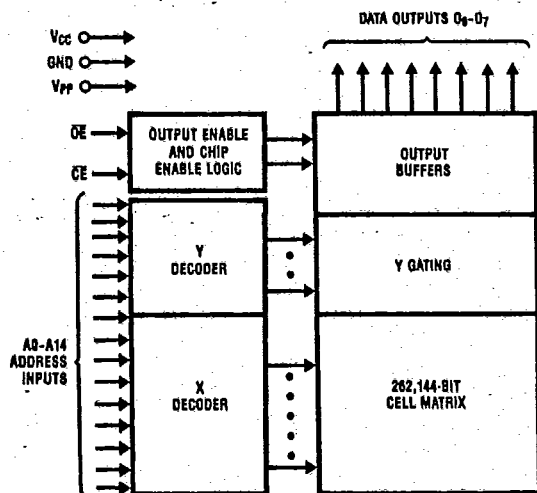
The NMC27C256 is packaged in a 28-pin dual in-line package with transparent lid. The transparent lid allows the user to expose the chip to ultraviolet light to erase the bit pattern. A new pattern can then be written electrically into the device by following the programming procedure.

This EPROM is fabricated with National's proprietary, time proven CMOS double-poly silicon gate technology which combines high performance and high density with low power consumption and excellent reliability.

### Features

- Clocked sense amps for fast access time down to 170 ns
- Low CMOS power consumption
  - Active power: 55 mW max
  - Standby power: 0.55 mW max
- Performance compatible to NSC800™ CMOS micro-processor
- Single 5V power supply
- Extended temperature range (NMC27C256QE),  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ , and military temperature range (NMC27C256QM),  $-55^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ , available
- Pin compatible with NMOS 256k EPROMs
- Fast and reliable programming (0.5 ms for most bytes)
- Static operation—no clocks required
- TTL, CMOS compatible inputs/outputs
- TRI-STATE® output
- Optimum EPROM for total CMOS systems

### Block Diagram



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Pin Names

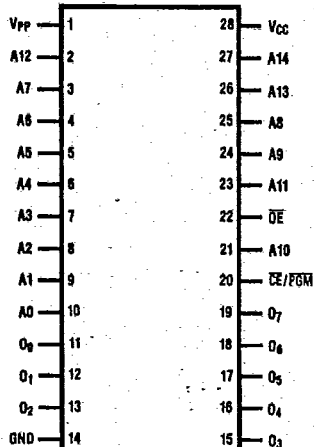
|        |               |
|--------|---------------|
| A0-A14 | Addresses     |
| CE     | Chip Enable   |
| OE     | Output Enable |
| O0-O7  | Outputs       |
| PGM    | Program       |
| NC     | No Connect    |

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## Connection Diagram

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| 27C512<br>27512 | 27C128<br>27128 | 27C64<br>2764   | 27C32<br>2732  | 27C16<br>2716  |
|-----------------|-----------------|-----------------|----------------|----------------|
| A15             | V <sub>PP</sub> | V <sub>PP</sub> |                |                |
| A12             | A12             | A12             |                |                |
| A7              | A7              | A7              | A7             | A7             |
| A6              | A6              | A6              | A6             | A6             |
| A5              | A5              | A5              | A5             | A5             |
| A4              | A4              | A4              | A4             | A4             |
| A3              | A3              | A3              | A3             | A3             |
| A2              | A2              | A2              | A2             | A2             |
| A1              | A1              | A1              | A1             | A1             |
| A0              | A0              | A0              | A0             | A0             |
| O <sub>0</sub>  | O <sub>0</sub>  | O <sub>0</sub>  | O <sub>0</sub> | O <sub>0</sub> |
| O <sub>1</sub>  | O <sub>1</sub>  | O <sub>1</sub>  | O <sub>1</sub> | O <sub>1</sub> |
| O <sub>2</sub>  | O <sub>2</sub>  | O <sub>2</sub>  | O <sub>2</sub> | O <sub>2</sub> |
| GND             | GND             | GND             | GND            | GND            |

NMC27C256Q  
Dual-In-Line Package

| 27C16<br>2716   | 27C32<br>2732      | 27C64<br>2764   | 27C128<br>27128 | 27C512<br>27512    |
|-----------------|--------------------|-----------------|-----------------|--------------------|
|                 |                    | V <sub>CC</sub> | V <sub>CC</sub> | V <sub>CC</sub>    |
|                 |                    | PGM             | PGM             | A14                |
| V <sub>CC</sub> | V <sub>CC</sub>    | NC              | A13             | A13                |
| A8              | A8                 | A8              | A8              | A8                 |
| A9              | A9                 | A9              | A9              | A9                 |
| V <sub>PP</sub> | A11                | A11             | A11             | A11                |
| OE              | OE/V <sub>PP</sub> | OE              | OE              | OE/V <sub>PP</sub> |
| A10             | A10                | A10             | A10             | A10                |
| CE/PGM          | CE                 | CE              | CE              | CE                 |
| O <sub>7</sub>  | O <sub>7</sub>     | O <sub>7</sub>  | O <sub>7</sub>  | O <sub>7</sub>     |
| O <sub>6</sub>  | O <sub>6</sub>     | O <sub>6</sub>  | O <sub>6</sub>  | O <sub>6</sub>     |
| O <sub>5</sub>  | O <sub>5</sub>     | O <sub>5</sub>  | O <sub>5</sub>  | O <sub>5</sub>     |
| O <sub>4</sub>  | O <sub>4</sub>     | O <sub>4</sub>  | O <sub>4</sub>  | O <sub>4</sub>     |
| O <sub>3</sub>  | O <sub>3</sub>     | O <sub>3</sub>  | O <sub>3</sub>  | O <sub>3</sub>     |

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Note: Socket compatible EPROM pin configurations are shown in the blocks adjacent to the NMC27C256 pins.

Order Number NMC27C256Q  
See NS Package Number J28AQCommercial Temp Range (0°C to +70°C)  
V<sub>CC</sub> = 5V ± 5%

| Parameter/Order Number | Access Time |
|------------------------|-------------|
| NMC27C256Q17           | 170         |
| NMC27C256Q20           | 200         |
| NMC27C256Q25           | 250         |

Commercial Temp Range (0°C to +70°C)  
V<sub>CC</sub> = 5V ± 10%

| Parameter/Order Number | Access Time |
|------------------------|-------------|
| NMC27C256Q200          | 200         |
| NMC27C256Q250          | 250         |
| NMC27C256Q300          | 300         |

Extended Temp Range (-40°C to +85°C)  
V<sub>CC</sub> = 5V ± 10%

| Parameter/Order Number | Access Time |
|------------------------|-------------|
| NMC27C256QE200         | 200         |
| NMC27C256QE250         | 250         |

Military Temp Range (-55°C to +125°C)  
V<sub>CC</sub> = 5V ± 10%

| Parameter/Order Number | Access Time |
|------------------------|-------------|
| NMC27C256QM250         | 250         |
| NMC27C256QM350         | 350         |

NOTE: For plastic DIP and surface mount PLCC package requirements please refer to NMC27C256BN data sheet.

## COMMERCIAL TEMPERATURE RANGE

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## Absolute Maximum Ratings (Note 1)

|   |                                 |
|---|---------------------------------|
| Temperature Under Bias  | -10°C to +80°C                  |
| Storage Temperature   | -65°C to +150°C                 |
| All Input Voltages with Respect to Ground (Note 10)               | +6.5V to -0.6V                  |
| All Output Voltages with Respect to Ground (Note 10)              | $V_{CC} + 1.0V$ to $GND - 0.6V$ |
| $V_{PP}$ Supply Voltage with Respect to Ground During Programming | +14.0V to -0.6V                 |

|  |                |
|--|----------------|
| Power Dissipation                              | 1.0W           |
| Lead Temperature (Soldering, 10 sec.)          | 300°C          |
| $V_{CC}$ Supply Voltage with Respect to Ground | +7.0V to -0.6V |

## Operating Conditions (Note 7)

|                         |              |
|-------------------------|--------------|
| Temperature Range       | 0°C to +70°C |
| $V_{CC}$ Power Supply   |              |
| NMC27C256Q17, 20, 25    | 5V ±5%       |
| NMC27C256Q200, 250, 300 | 5V ±10%      |

## READ OPERATION

## DC Electrical Characteristics

| Symbol                | Parameter                              | Conditions   | Min            | Typ | Max          | Units   |
|-----------------------|--|--|----------------|-----|--------------|---------|
| $I_{LI}$              | Input Load Current                     | $V_{IN} = V_{CC}$ or GND   |                |     | 10           | $\mu A$ |
| $I_{LO}$              | Output Leakage Current                 | $V_{OUT} = V_{CC}$ or GND, $\overline{CE} = V_{IH}$                                  |                |     | 10           | $\mu A$ |
| $I_{CC1}$<br>(Note 9) | $V_{CC}$ Current (Active) TTL Inputs   | $\overline{CE} = V_{IL}$ , $f = 5$ MHz<br>Inputs = $V_{IH}$ or $V_{IL}$ , I/O = 0 mA |                | 6   | 20           | mA      |
| $I_{CC2}$<br>(Note 9) | $V_{CC}$ Current (Active) CMOS Inputs  | $\overline{CE} = GND$ , $f = 5$ MHz<br>Inputs = $V_{CC}$ or GND, I/O = 0 mA          |                | 3   | 10           | mA      |
| $I_{CCSB1}$           | $V_{CC}$ Current (Standby) TTL Inputs  | $\overline{CE} = V_{IH}$   |                | 0.1 | 1            | mA      |
| $I_{CCSB2}$           | $V_{CC}$ Current (Standby) CMOS Inputs | $\overline{CE} = V_{CC}$   |                | 0.5 | 100          | $\mu A$ |
| $I_{PP}$              | $V_{PP}$ Load Current                  | $V_{PP} = V_{CC}$  |                |     | 10           | $\mu A$ |
| $V_{IL}$              | Input Low Voltage                      |  | -0.1           |     | 0.8          | V       |
| $V_{IH}$              | Input High Voltage                     |  | 2.0            |     | $V_{CC} + 1$ | V       |
| $V_{OL1}$             | Output Low Voltage                     | $I_{OL} = 2.1$ mA  |                |     | 0.45         | V       |
| $V_{OH1}$             | Output High Voltage                    | $I_{OH} = -400$ $\mu A$  | 2.4            |     |              | V       |
| $V_{OL2}$             | Output Low Voltage                     | $I_{OL} = 0$ $\mu A$   |                |     | 0.1          | V       |
| $V_{OH2}$             | Output High Voltage                    | $I_{OH} = 0$ $\mu A$   | $V_{CC} - 0.1$ |     |              | V       |

## AC Electrical Characteristics

| Symbol           | Parameter   | Conditions                               | NMC27C256 |     |           |     |           |     |      |     | Units |
|------------------|---|--|-----------|-----|-----------|-----|-----------|-----|------|-----|-------|
|                  |   |  | Q17       |     | Q20, Q200 |     | Q25, Q250 |     | Q300 |     |       |
|                  |   |  | Min       | Max | Min       | Max | Min       | Max | Min  | Max |       |
| t <sub>ACO</sub> | Address to Output Delay   | $\overline{CE} = \overline{OE} = V_{IL}$ |           | 170 |           | 200 |           | 250 |      | 300 | ns    |
| t <sub>CE</sub>  | $\overline{CE}$ to Output Delay   | $\overline{OE} = V_{IL}$                 |           | 170 |           | 200 |           | 250 |      | 300 | ns    |
| t <sub>OE</sub>  | $\overline{OE}$ to Output Delay   | $\overline{CE} = V_{IL}$                 |           | 75  |           | 75  |           | 100 |      | 120 | ns    |
| t <sub>DF</sub>  | $\overline{OE}$ High to Output Float  | $\overline{CE} = V_{IL}$                 | 0         | 60  | 0         | 60  | 0         | 60  | 0    | 105 | ns    |
| t <sub>CF</sub>  | $\overline{CE}$ High to Output Float  | $\overline{OE} = V_{IL}$                 | 0         | 60  | 0         | 60  | 0         | 60  | 0    | 105 | ns    |
| t <sub>OH</sub>  | Output Hold from Addresses, $\overline{CE}$ or $\overline{OE}$ , Whichever Occurred First | $\overline{CE} = \overline{OE} = V_{IL}$ | 0         |     | 0         |     | 0         |     | 0    |     | ns    |

**MILITARY AND EXTENDED TEMPERATURE RANGE****Absolute Maximum Ratings** (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Temperature Under Bias      Operating Temp Range

Storage Temperature       $-65^{\circ}\text{C}$  to  $+150^{\circ}\text{C}$

All Input Voltages with Respect to Ground (Note 10)       $+6.5\text{V}$  to  $-0.6\text{V}$

All Output Voltages with Respect to Ground (Note 10)       $V_{\text{CC}} + 1.0\text{V}$  to  $\text{GND} - 0.6\text{V}$

$V_{\text{PP}}$  Supply Voltage with Respect to Ground During Programming       $+14.0\text{V}$  to  $-0.6\text{V}$

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Power Dissipation      1.0W

Lead Temperature (Soldering, 10 sec.)       $300^{\circ}\text{C}$

$V_{\text{CC}}$  Supply Voltage with Respect to Ground       $+7.0\text{V}$  to  $-0.6\text{V}$

**Operating Conditions** (Note 7)

Temperature Range  
NMC27C256QE200, 250       $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$   
NMC27C256QM250, M350       $-55^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$

$V_{\text{CC}}$  Power Supply       $5\text{V} \pm 10\%$

**READ OPERATION****DC Electrical Characteristics**

| Symbol                       | Parameter  | Conditions  | Min                   | Typ | Max                 | Units         |
|------------------------------|--|---|-----------------------|-----|---------------------|---------------|
| $I_{\text{LI}}$              | Input Load Current                               | $V_{\text{IN}} = V_{\text{CC}}$ or GND  |                       |     | 10                  | $\mu\text{A}$ |
| $I_{\text{LO}}$              | Output Leakage Current                           | $V_{\text{OUT}} = V_{\text{CC}}$ or GND, $\overline{\text{CE}} = V_{\text{IH}}$   |                       |     | 10                  | $\mu\text{A}$ |
| $I_{\text{CC1}}$<br>(Note 9) | $V_{\text{CC}}$ Current (Active)<br>TTL Inputs   | $\overline{\text{CE}} = V_{\text{IL}}$ , $f = 5\text{ MHz}$<br>Inputs = $V_{\text{IH}}$ or $V_{\text{IL}}$ , I/O = 0 mA |                       | 6   | 20                  | mA            |
| $I_{\text{CC2}}$<br>(Note 9) | $V_{\text{CC}}$ Current (Active)<br>CMOS Inputs  | $\overline{\text{CE}} = \text{GND}$ , $f = 5\text{ MHz}$<br>Inputs = $V_{\text{CC}}$ or GND, I/O = 0 mA                 |                       | 3   | 10                  | mA            |
| $I_{\text{CCSB1}}$           | $V_{\text{CC}}$ Current (Standby)<br>TTL Inputs  | $\overline{\text{CE}} = V_{\text{IH}}$  |                       | 0.1 | 1                   | mA            |
| $I_{\text{CCSB2}}$           | $V_{\text{CC}}$ Current (Standby)<br>CMOS Inputs | $\overline{\text{CE}} = V_{\text{CC}}$  |                       | 0.5 | 100                 | $\mu\text{A}$ |
| $I_{\text{PP}}$              | $V_{\text{PP}}$ Load Current                     | $V_{\text{PP}} = V_{\text{CC}}$   |                       |     | 10                  | $\mu\text{A}$ |
| $V_{\text{IL}}$              | Input Low Voltage                                |   | -0.1                  |     | 0.8                 | V             |
| $V_{\text{IH}}$              | Input High Voltage                               |   | 2.0                   |     | $V_{\text{CC}} + 1$ | V             |
| $V_{\text{OL1}}$             | Output Low Voltage                               | $I_{\text{OL}} = 2.1\text{ mA}$   |                       |     | 0.45                | V             |
| $V_{\text{OH1}}$             | Output High Voltage                              | $I_{\text{OH}} = -400\text{ }\mu\text{A}$   | 2.4                   |     |                     | V             |
| $V_{\text{OL2}}$             | Output Low Voltage                               | $I_{\text{OH}} = 0\text{ }\mu\text{A}$  |                       |     | 0.1                 | V             |
| $V_{\text{OH2}}$             | Output High Voltage                              | $I_{\text{OH}} = 0\text{ }\mu\text{A}$  | $V_{\text{CC}} - 0.1$ |     |                     | V             |

**AC Electrical Characteristics**

| Symbol           | Parameter   | Conditions  | NMC27C256Q |     |              |     |      |     | Units |
|------------------|---|---|------------|-----|--------------|-----|------|-----|-------|
|                  |   |   | E200       |     | E250<br>M250 |     | M350 |     |       |
|                  |   |   | Min        | Max | Min          | Max | Min  | Max |       |
| t <sub>ACC</sub> | Address to Output Delay   | $\overline{\text{OE}} = \overline{\text{OE}} = V_{\text{IL}}$ |            | 200 |              | 250 |      | 350 | ns    |
| t <sub>CE</sub>  | $\overline{\text{OE}}$ to Output Delay  | $\overline{\text{OE}} = V_{\text{IL}}$                        |            | 200 |              | 250 |      | 350 | ns    |
| t <sub>OE</sub>  | $\overline{\text{OE}}$ to Output Delay  | $\overline{\text{OE}} = V_{\text{IL}}$                        |            | 75  |              | 100 |      | 120 | ns    |
| t <sub>DF</sub>  | $\overline{\text{OE}}$ High to Output Float   | $\overline{\text{OE}} = V_{\text{IL}}$                        | 0          | 60  | 0            | 60  | 0    | 105 | ns    |
| t <sub>OH</sub>  | Output Hold from Addresses,<br>$\overline{\text{CE}}$ or $\overline{\text{OE}}$ Whichever<br>Occurred First | $\overline{\text{CE}} = \overline{\text{OE}} = V_{\text{IL}}$ | 0          |     | 0            |     | 0    |     | ns    |
| t <sub>CF</sub>  | $\overline{\text{CE}}$ High to Output Float   | $\overline{\text{OE}} = V_{\text{IL}}$                        | 0          | 60  | 0            | 60  | 0    | 105 | ns    |

**Capacitance**  $T_A = +25^\circ\text{C}$ ,  $f = 1\text{ MHz}$  (Note 2)

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| Symbol    | Parameter          | Conditions            | Typ | Max | Units |
|-----------|--------------------|-----------------------|-----|-----|-------|
| $C_{IN}$  | Input Capacitance  | $V_{IN} = 0\text{V}$  | 6   | 12  | pF    |
| $C_{OUT}$ | Output Capacitance | $V_{OUT} = 0\text{V}$ | 9   | 12  | pF    |

**AC Test Conditions**

Output Load

1 TTL Gate and  
 $C_L = 100\text{ pF}$  (Note 8)

Timing Measurement Reference Level

Inputs -  
Outputs

0.8V and 2V

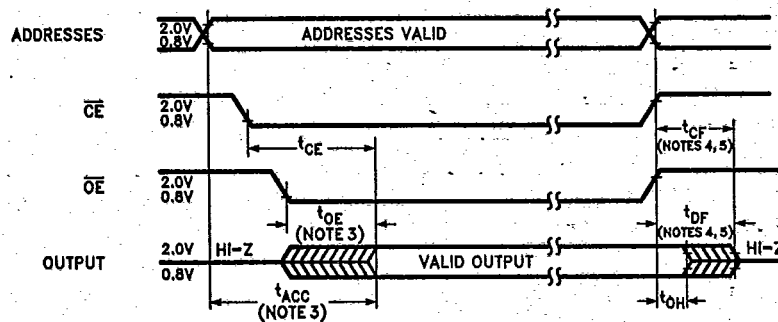
Input Rise and Fall Times

 $\leq 5\text{ ns}$ 

0.8V and 2V

Input Pulse Levels

0.45V to 2.4V

**AC Waveforms** (Notes 6, 7 & 9)

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**Note 1:** Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**Note 2:** This parameter is only sampled and is not 100% tested.

**Note 3:**  $\overline{OE}$  may be delayed up to  $t_{ACC} - t_{OE}$  after the falling edge of  $\overline{CE}$  without impacting  $t_{ACC}$ .

**Note 4:** The  $t_{DF}$  and  $t_{CF}$  compare level is determined as follows:

High to TRI-STATE, the measured  $V_{OH1}$  (DC) - 0.10V;

Low to TRI-STATE, the measured  $V_{OL1}$  (DC) + 0.10V.

**Note 5:** TRI-STATE may be attained using  $\overline{OE}$  or  $\overline{CE}$ .

**Note 6:** The power switching characteristics of EPROMs require careful device decoupling. It is recommended that at least a 0.1  $\mu\text{F}$  ceramic capacitor be used on every device between  $V_{CC}$  and GND.

**Note 7:** The outputs must be restricted to  $V_{CC} + 1.0\text{V}$  to avoid latch-up and device damage.

**Note 8:** 1 TTL Gate:  $I_{OL} = 1.6\text{ mA}$ ,  $I_{OH} = -400\text{ }\mu\text{A}$ .

$C_L$ : 100 pF includes fixture capacitance.

**Note 9:**  $V_{PP}$  may be connected to  $V_{CC}$  except during programming.

**Note 10:** Inputs and outputs can undershoot to -2.0V for 20 ns Max.

## Programming Characteristics (Notes 1, 2, 3 &amp; 4)

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| Symbol    | Parameter  | Conditions                                 | Min  | Typ  | Max  | Units       |
|-----------|--|--|------|------|------|-------------|
| $t_{AS}$  | Address Setup Time                               |  | 2    |      |      | $\mu s$     |
| $t_{OES}$ | $\overline{OE}$ Setup Time                       |  | 2    |      |      | $\mu s$     |
| $t_{VPS}$ | $V_{PP}$ Setup Time                              |  | 2    |      |      | $\mu s$     |
| $t_{VCS}$ | $V_{CC}$ Setup Time                              |  | 2    |      |      | $\mu s$     |
| $t_{DS}$  | Data Setup Time                                  |  | 2    |      |      | $\mu s$     |
| $t_{AH}$  | Address Hold Time                                |  | 0    |      |      | $\mu s$     |
| $t_{DH}$  | Data Hold Time                                   |  | 2    |      |      | $\mu s$     |
| $t_{DF}$  | Output Enable to Output Float Delay              | $\overline{CE} = V_{IL}$                   | 0    |      | 130  | ns          |
| $t_{PW}$  | Program Pulse Width                              |  | 0.5  | 0.5  | 10   | ms          |
| $t_{OE}$  | Data Valid from $\overline{OE}$                  | $\overline{CE} = V_{IL}$                   |      |      | 150  | ns          |
| $I_{PP}$  | $V_{PP}$ Supply Current During Programming Pulse | $\overline{CE} = V_{IL}$<br>$PGM = V_{IL}$ |      |      | 30   | mA          |
| $I_{CC}$  | $V_{CC}$ Supply Current                          |  |      |      | 10   | mA          |
| $T_A$     | Temperature Ambient                              |  | 20   | 25   | 30   | $^{\circ}C$ |
| $V_{CC}$  | Power Supply Voltage                             |  | 5.75 | 6.0  | 6.25 | V           |
| $V_{PP}$  | Programming Supply Voltage                       |  | 12.2 | 13.0 | 13.3 | V           |
| $t_{FR}$  | Input Rise, Fall Time                            |  | 5    |      |      | ns          |
| $V_{IL}$  | Input Low Voltage                                |  |      | 0.0  | 0.45 | V           |
| $V_{IH}$  | Input High Voltage                               |  | 2.4  | 4.0  |      | V           |
| $t_{IN}$  | Input Timing Reference Voltage                   |  | 0.8  | 1.5  | 2.0  | V           |
| $t_{OUT}$ | Output Timing Reference Voltage                  |  | 0.8  | 1.5  | 2.0  | V           |

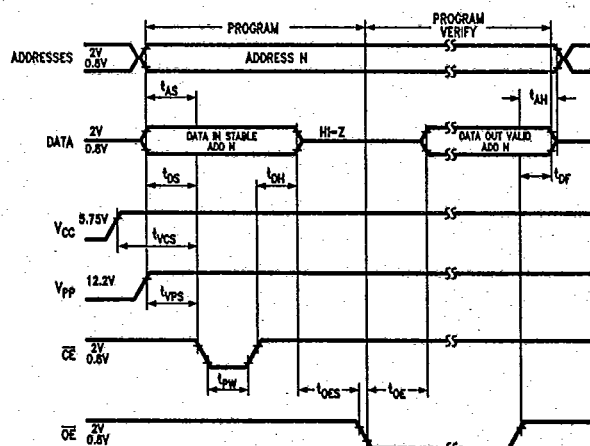
Note 1: National's standard product warranty applies only to devices programmed to specifications described herein.

Note 2:  $V_{CC}$  must be applied simultaneously or before  $V_{PP}$  and removed simultaneously or after  $V_{PP}$ . The EPROM must not be inserted into or removed from a board with voltage applied to  $V_{PP}$  or  $V_{CC}$ .

Note 3: The maximum absolute allowable voltage which may be applied to the  $V_{PP}$  pin during programming is 14V. Care must be taken when switching the  $V_{PP}$  supply to prevent any overshoot from exceeding this 14V maximum specification. At least a 0.1  $\mu F$  capacitor is required across  $V_{PP}$ ,  $V_{CC}$  to GND to suppress spurious voltage transients which may damage the device.

Note 4: Programming and program verify are tested with the Interactive Program Algorithm, at typical power supply voltages and timings.

## Programming Waveforms (Note 3)



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## Interactive Programming Algorithm Flow Chart

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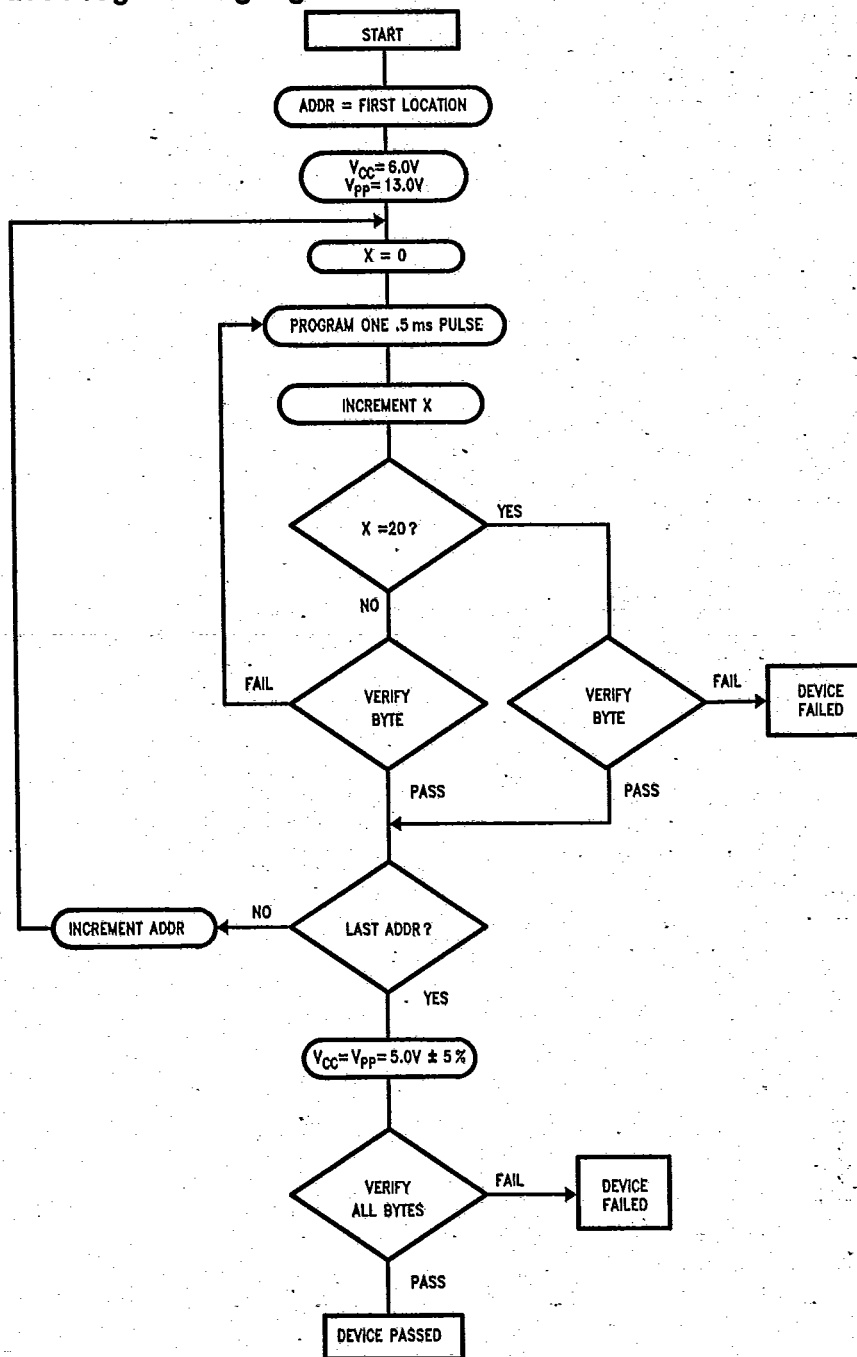


FIGURE 1

TL/D/7512-5

## Functional Description

### DEVICE OPERATION

The six modes of operation of the NMC27C256 are listed in Table I. It should be noted that all inputs for the six modes are at TTL levels. The power supplies required are  $V_{CC}$  and  $V_{PP}$ . The  $V_{PP}$  power supply must be at 13.0V during the three programming modes, and must be at 5V in the other three modes. The  $V_{CC}$  power supply must be at 6V during the three programming modes, and at 5V in the other three modes.

#### Read Mode

The NMC27C256 has two control functions, both of which must be logically active in order to obtain data at the outputs. Chip Enable ( $\overline{CE}$ ) is the power control and should be used for device selection. Output Enable ( $\overline{OE}$ ) is the output control and should be used to gate data to the output pins, independent of device selection. Assuming that addresses are stable, address access time ( $t_{ACC}$ ) is equal to the delay from  $\overline{CE}$  to output ( $t_{CE}$ ). Data is available at the outputs  $t_{OE}$  after the falling edge of  $\overline{OE}$ , assuming that  $\overline{CE}$  has been low and addresses have been stable for at least  $t_{ACC} - t_{OE}$ .

The sense amps are clocked for fast access time.  $V_{CC}$  should therefore be maintained at operating voltage during read and verify. If  $V_{CC}$  temporarily drops below the spec. voltage (but not to ground) an address transition must be performed after the drop to ensure proper output data.

#### Standby Mode

The NMC27C256 has a standby mode which reduces the active power dissipation by 99%, from 55 mW to 0.55 mW. The NMC27C256 is placed in the standby mode by applying a CMOS high signal to the  $\overline{CE}$  input. When in standby mode, the outputs are in a high impedance state, independent of the  $\overline{OE}$  input.

#### Output OR-Tying

Because NMC27C256s are usually used in larger memory arrays, National has provided a 2-line control function that accommodates this use of multiple memory connections. The 2-line control function allows for:

- the lowest possible memory power dissipation, and
- complete assurance that output bus contention will not occur.

To most efficiently use these two control lines, it is recommended that  $\overline{CE}$  (pin 20) be decoded and used as the primary device selecting function, while  $\overline{OE}$  (pin 22) be made a common connection to all devices in the array and connected to the READ line from the system control bus. This assures that all deselected memory devices are in their low power standby modes and that the output pins are active only when data is desired from a particular memory device.

#### Programming

CAUTION: Exceeding 14V on pin 1 ( $V_{PP}$ ) will damage the NMC27C256.

Initially, and after each erasure, all bits of the NMC27C256 are in the "1" state. Data is introduced by selectively programming "0s" into the desired bit locations. Although only "0s" will be programmed, both "1s" and "0s" can be presented in the data word. The only way to change a "0" to a "1" is by ultraviolet light erasure.

The NMC27C256 is in the programming mode when the  $V_{PP}$  power supply is at 13.0V and  $\overline{OE}$  is at  $V_{IH}$ . It is required that at least a 0.1  $\mu$ F capacitor be placed across  $V_{PP}$ ,  $V_{CC}$  to ground to suppress spurious voltage transients which may damage the device. The data to be programmed is applied 8 bits in parallel to the data output pins. The levels required for the address and data inputs are TTL.

When the address and data are stable, an active low TTL program pulse is applied to the  $\overline{CE}/\text{PGM}$  input. A program pulse must be applied at each address location to be programmed. Any location may be programmed at any time—either individually, sequentially, or at random. The NMC27C256 is designed to be programmed with interactive programming, where each address is programmed with a series of 0.5 ms pulses until it verifies (up to a maximum of 20 pulses or 10 ms). The NMC27C256 must not be programmed with a DC signal applied to the  $\overline{CE}/\text{PGM}$  input.

Programming multiple NMC27C256s in parallel with the same data can be easily accomplished due to the simplicity of the programming requirements. Like inputs of the paralleled NMC27C256s may be connected together when they are programmed with the same data. A low level TTL pulse applied to the  $\overline{CE}/\text{PGM}$  input programs the paralleled NMC27C256s.

TABLE I. Mode Selection

| Mode            | Pins | $\overline{CE}/\text{PGM}$<br>(20) | $\overline{OE}$<br>(22) | $V_{PP}$<br>(1) | $V_{CC}$<br>(28) | Outputs<br>(11-13, 15-19) |
|-----------------|------|------------------------------------|-------------------------|-----------------|------------------|---------------------------|
| Read            |      | $V_{IL}$                           | $V_{IL}$                | 5V              | 5V               | $D_{OUT}$                 |
| Standby         |      | $V_{IH}$                           | Don't Care              | 5V              | 5V               | Hi-Z                      |
| Program         |      | $V_{IL}$                           | $V_{IH}$                | 13.0V           | 6V               | $D_{IN}$                  |
| Program Verify  |      | $V_{IH}$                           | $V_{IL}$                | 13.0V           | 6V               | $D_{OUT}$                 |
| Program Inhibit |      | $V_{IH}$                           | $V_{IH}$                | 13.0V           | 6V               | Hi-Z                      |
| Output Disable  |      | Don't Care                         | $V_{IH}$                | 5V              | 5V               | Hi-Z                      |



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NMC27C256

**Functional Description (Continued)****Program Inhibit**

Programming multiple NMC27C256s in parallel with different data is also easily accomplished. Except for  $\overline{CE}$  all like inputs (including  $\overline{OE}$ ) of the parallel NMC27C256s may be common. A TTL low level program pulse applied to an NMC27C256's  $\overline{CE}/\overline{PGM}$  input with  $V_{PP}$  at 13.0V will program that NMC27C256. A TTL high level  $\overline{CE}$  input inhibits the other NMC27C256s from being programmed.

**Program Verify**

A verify should be performed on the programmed bits to determine whether they were correctly programmed. The verify may be performed with  $V_{PP}$  at 13.0V.  $V_{PP}$  must be at  $V_{CC}$ , except during programming and program verify.

**ERASURE CHARACTERISTICS**

The erasure characteristics of the NMC27C256 are such that erasure begins to occur when exposed to light with wavelengths shorter than approximately 4000 Angstroms ( $\text{\AA}$ ). It should be noted that sunlight and certain types of fluorescent lamps have wavelengths in the 3000 $\text{\AA}$ -4000 $\text{\AA}$  range.

After programming, opaque labels should be placed over the NMC27C256's window to prevent unintentional erasure. Covering the window will also prevent temporary functional failure due to the generation of photo currents.

The recommended erasure procedure for the NMC27C256 is exposure to short wave ultraviolet light which has a wavelength of 2537 Angstroms ( $\text{\AA}$ ). The integrated dose (i.e., UV intensity  $\times$  exposure time) for erasure should be a minimum of 15W-sec/cm<sup>2</sup>.

The NMC27C256 should be placed within 1 inch of the lamp tubes during erasure. Some lamps have a filter on their tubes which should be removed before erasure. Table II

shows the minimum NMC27C256 erasure time for various light intensities.

An erasure system should be calibrated periodically. The distance from lamp to unit should be maintained at one inch. The erasure time increases as the square of the distance. (If distance is doubled the erasure time increases by a factor of 4.) Lamps lose intensity as they age. When a lamp is changed, the distance has changed or the lamp has aged, the system should be checked to make certain full erasure is occurring. Incomplete erasure will cause symptoms that can be misleading. Programmers, components, and even system designs have been erroneously suspected when incomplete erasure was the problem.

**SYSTEM CONSIDERATION**

The power switching characteristics of EPROMs require careful decoupling of the devices. The supply current,  $I_{CC}$ , has three segments that are of interest to the system designer—the standby current level, the active current level, and the transient current peaks that are produced by voltage transitions on input pins. The magnitude of these transient current peaks is dependent on the output capacitance loading of the device. The associated  $V_{CC}$  transient voltage peaks can be suppressed by properly selected decoupling capacitors. It is recommended that at least a 0.1  $\mu\text{F}$  ceramic capacitor be used on every device between  $V_{CC}$  and GND. This should be a high frequency capacitor of low inherent inductance. In addition, at least a 4.7  $\mu\text{F}$  bulk electrolytic capacitor should be used between  $V_{CC}$  and GND for each eight devices. The bulk capacitor should be located near where the power supply is connected to the array. The purpose of the bulk capacitor is to overcome the voltage drop caused by the inductive effects of the PC board traces.

**TABLE II. Minimum NMC27C256 Erasure Time**

| Light Intensity<br>(Micro-Watts/cm <sup>2</sup> ) | Erasure Time<br>(Minutes) |
|---|---------------------------|
| 15,000  | 20                        |
| 10,000  | 25                        |
| 5,000   | 50                        |